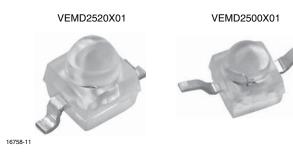


**Vishay Semiconductors** 

### **Silicon PIN Photodiode**



VEMD2500X01 and VEMD2520X01 are high speed and high sensitive PIN photodiodes in a clear epoxy, miniature

surface mount package (SMD) with dome lens. The photo

#### FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 qualified
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 15^{\circ}$
- Package matched with IR emitter series VSMB2000X01
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **APPLICATIONS**

• High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μA)	φ (deg)	λ <sub>0.1</sub> (nm)	
VEMD2500X01	12	± 15	350 to 1120	
VEMD2520X01	12	± 15	350 to 1120	

#### Note

DESCRIPTION

• Test conditions see table "Basic Characteristics"

sensitive area of the chip is 0.23 mm<sup>2</sup>.

ORDERING INFORMATI	ON		
ORDERING CODE	PACKAGING REMARKS PACKAGE		PACKAGE FORM
VEMD2500X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing
VEMD2520X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing

#### Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	60	V
Power dissipation	T <sub>amb</sub> ≤ 25 °C	Pv	215	mW
Junction temperature		Тj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	Acc. reflow solder profile fig. 7	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	Acc. J-STD-051	R <sub>thJA</sub>	250	K/W

This datasheet is subject to change without notice. THE PRODUCT DESCRIBED HEREIN AND THIS DATASHEET ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000





Vishay Semiconductors

Silicon PIN Photodiode



PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>		1		V
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	32			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		1	10	nA
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD		4		pF
	$V_R = 5 V, f = 1 MHz, E = 0$	CD		1.3		pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	TK <sub>Vo</sub>		- 2.6		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	l <sub>k</sub>		11		μA
Temperature coefficient of $I_k$	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	8.5	12	17	μA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		λρ		900		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		350 to 1120		nm
Rise time	$V_{\text{R}} = 10 \text{ V}, \text{ R}_{\text{L}} = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall time	$V_{R} = 10 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$	t <sub>f</sub>		100		ns

### BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

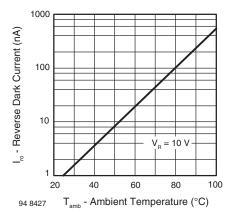


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

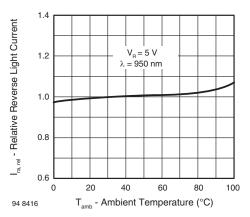


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



### Silicon PIN Photodiode

**Vishay Semiconductors** 

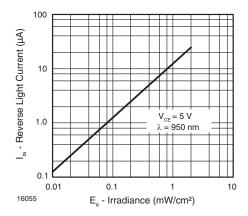


Fig. 3 - Reverse Light Current vs. Irradiance

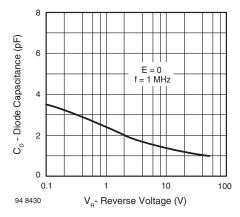


Fig. 4 - Diode Capacitance vs. Reverse Voltage

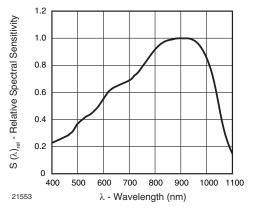


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

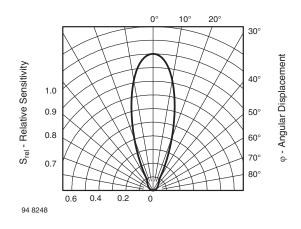


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

Vishay Semiconductors

Silicon PIN Photodiode

DRYPACK

**FLOOR LIFE** 

Floor life: 4 weeks

DRYING

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during

transportation and storage. Each bag contains a desiccant.

Floor life (time between soldering and removing from MBB)

In case of moisture absorption devices should be baked

before soldering. Conditions see J-STD-020 or label.

Devices taped on reel dry using recommended conditions

must not exceed the time indicated on MBB label:

Moisture sensitivity level 2a, acc. to J-STD-020.

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

192 h at 40 °C (+ 5 °C), RH < 5 %.



#### **REFLOW SOLDER PROFILE**

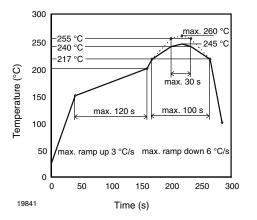


Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

2.3 ± 0.2

Cathode

Drawing-No.: 6.544-5391.02-4 Issue: 2; 18.03.10 <sup>21517</sup>

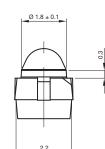
#### PACKAGE DIMENSIONS in millimeters: VEMD2500X01

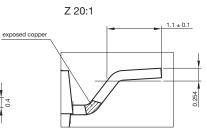
# 

 $2.3 \pm 0.2$ 

Pin ID

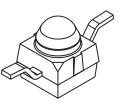
6.7







Not indicated tolerances ± 0.1



www.vishay.com

For technical questions, contact: detectortechsupport@vishay.com

Anode

Solder pad proposal acc. IPC 7351

Ø 2.3 ± 0.1

Document Number: 83294 Rev. 1.1, 22-Mar-11

This datasheet is subject to change without notice.

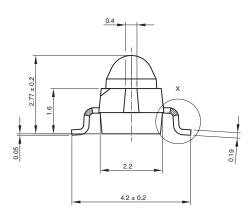
THE PRODUCT DESCRIBED HEREIN AND THIS DATASHEET ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

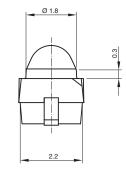


Silicon PIN Photodiode

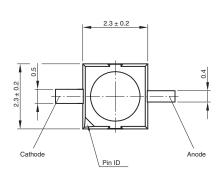
**Vishay Semiconductors** 

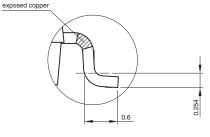
### PACKAGE DIMENSIONS in millimeters: VEMD2520X01





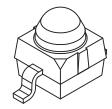


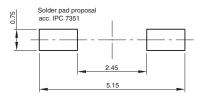






Not indicated tolerances ± 0.1





Drawing-No.: 6.544-5383.02-4 Issue: 4; 18.03.10 21488

Document Number: 83294 Rev. 1.1, 22-Mar-11

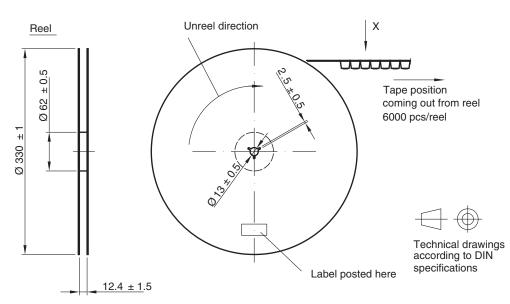
This datasheet is subject to change without notice. THE PRODUCT DESCRIBED HEREIN AND THIS DATASHEET ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

**Vishay Semiconductors** 

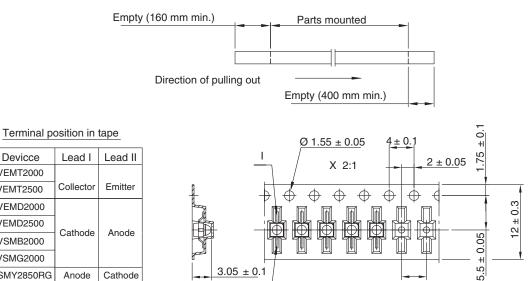
Silicon PIN Photodiode



### TAPING AND REEL DIMENSIONS in millimeters: VEMD2500X01



Leader and trailer tape:



4 ± 0.1

Drawing-No.: 9.800-5100.01-4

Issue: 2; 18.03.10 21572

Devicce

**VEMT2000** 

**VEMT2500** 

VEMD2000

VEMD2500

VSMB2000 VSMG2000

VSMY2850RG

www.vishay.com 6

Ш

Document Number: 83294 Rev. 1.1, 22-Mar-11

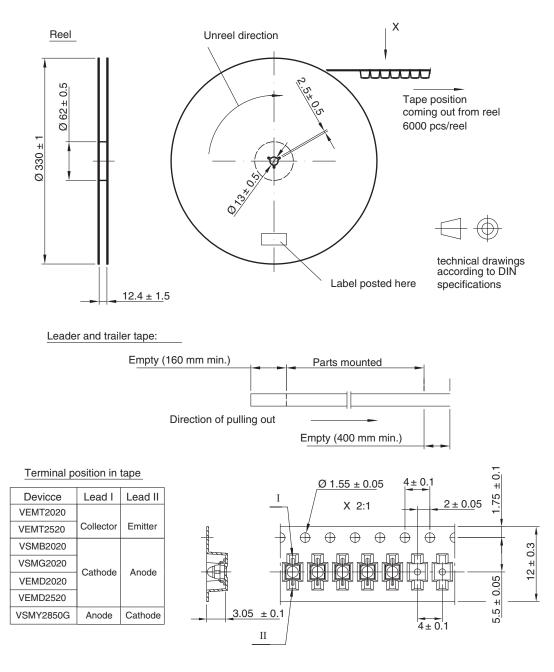
This datasheet is subject to change without notice. THE PRODUCT DESCRIBED HEREIN AND THIS DATASHEET ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Silicon PIN Photodiode

**Vishay Semiconductors** 

#### TAPING AND REEL DIMENSIONS in millimeters: VEMD2520X01



Drawing-No.: 9.800-5091.01-4 Issue: 3; 18.03.09 21571

This datasheet is subject to change without notice. THE PRODUCT DESCRIBED HEREIN AND THIS DATASHEET ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.